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Pages 1 to 17

**DIODES, SILICON, POWER RECTIFIER,  
FAST RECOVERY,  
BASED ON TYPES BYV 27/50, BYV 27/100  
AND BYV 27/150  
ESA/SCC Detail Specification No. 5103/025**



**space components  
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**DOCUMENTATION CHANGE NOTICE**

Rev. Letter	Rev. Date	Reference	CHANGE Item	Approved DCR No.
'A'	July '93	P1. Cover Page P2. DCN P9. Para. 4.2.2 : PIND deviation amended P10. Para. 4.2.3 : Radiographic Inspection deviation deleted, subsequent deviation renumbered P16. Table 3 : Note 4 deleted		None None 21043 21049 21047
<p>This document has been transferred from hardcopy to electronic format. The content is unchanged but minor differences in presentation exist.</p>				

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### APPENDICES (Applicable to specific Manufacturers only)

None.

**1. GENERAL****1.1 SCOPE**

This specification details the ratings, physical and electrical characteristics, test and inspection data for Diodes, Silicon, Power Rectifier, Fast Recovery, based on Types BYV 27/50, BYV 27/100 and BYV 27/150.

It shall be read in conjunction with ESA/SCC Generic Specification No. 5000, the requirements of which are supplemented herein.

**1.2 COMPONENT TYPE VARIANTS**

Variants of the basic diodes specified herein, which are also covered by this specification, are listed in Table 1(a).

**1.3 MAXIMUM RATINGS**

The maximum ratings, which shall not be exceeded at any time during use or storage, applicable to the diodes specified herein, are scheduled in Table 1(b).

**1.4 PARAMETER DERATING INFORMATION**

The derating information applicable to the diodes specified herein is shown in Figure 1.

**1.5 PHYSICAL DIMENSIONS**

The physical dimensions of the diodes specified herein are shown in Figure 2.

**1.6 FUNCTIONAL DIAGRAM**

The functional diagram, showing lead identification, of the diodes specified herein, is shown in Figure 3.

**2. APPLICABLE DOCUMENTS**

The following documents form part of this specification and shall be read in conjunction with it:-

- (a) ESA/SCC Generic Specification No. 5000 for Discrete Semiconductors.
- (b) MIL-STD-202, Test Methods for Electronic and Electrical Component Parts.
- (c) MIL-STD-750, Test Methods and Procedures for Semiconductor Devices.

**TABLE 1(a) - TYPE VARIANTS**

(1) VARIANT	(2) BASED ON TYPE	(3) $V_R$ (V)	(4) $V_{RWM}$ (V)	(5) $t_{rr}$ ( $\mu$ s)	(6) C (pF)	(7) $V_{(BR)}$ min. at $I_R = 100\mu$ A (V)	(8) Lead Material and Finish	(9) Figure
04	BYV27/50	44	50	25	60	60	K3 or K4	2
05	BYV27/100	88	100	25	60	110	K3 or K4	2
06	BYV27/150	132	150	25	60	160	K3 or K4	2

**TABLE 1(b) - MAXIMUM RATINGS**

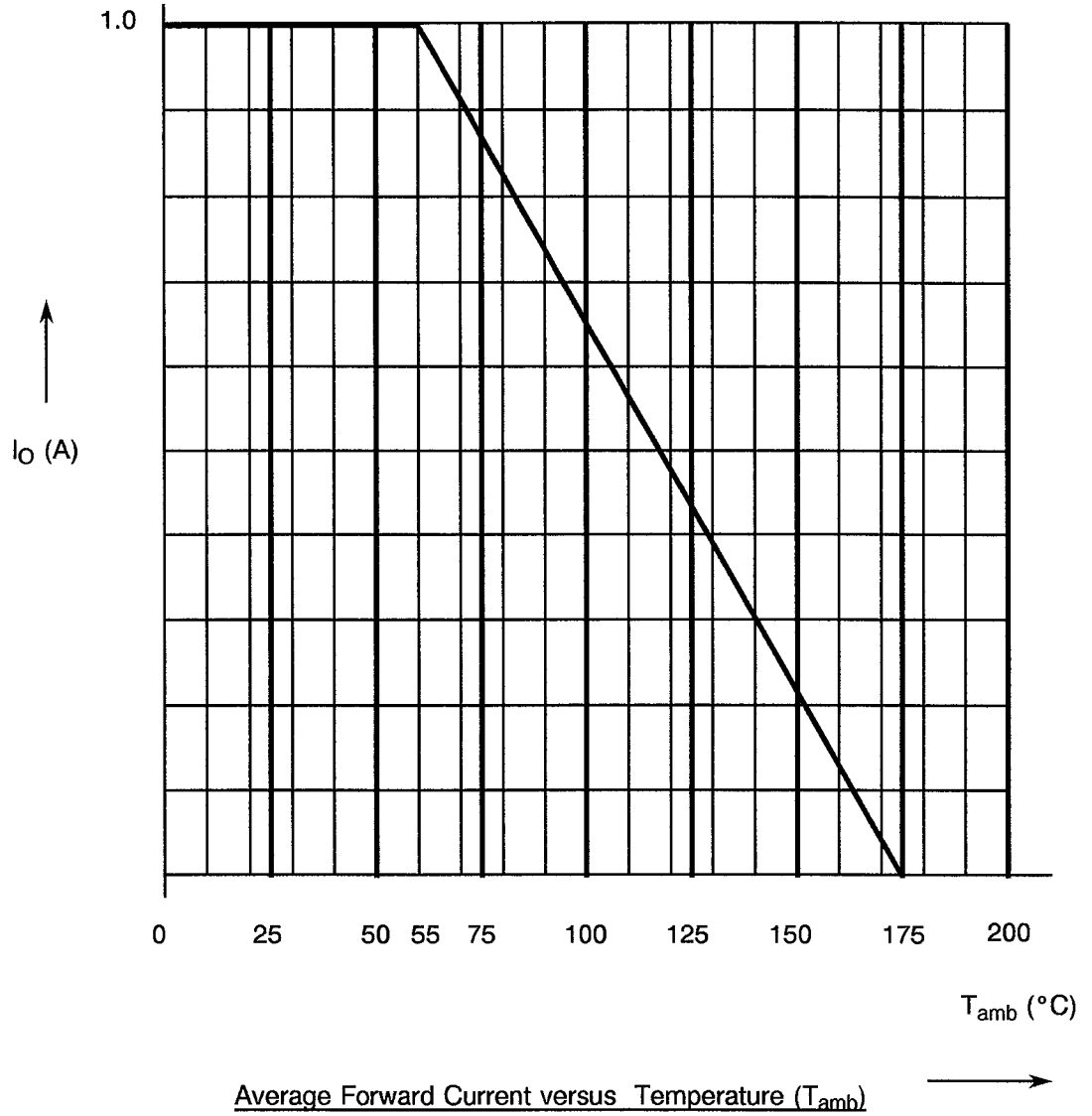
No.	CHARACTERISTIC	SYMBOL	MAXIMUM RATING	UNIT	REMARKS
1	Surge Forward Current	$I_{FSM}$	35	A(pk)	$T_{amb} = +55^\circ\text{C}$ $I_O = 1.0\text{A}$ $t_p = 8.3\text{ms}$
2	Average Forward Current	$I_O$	1.0 (1)	Adc	$T_{amb} = +55^\circ\text{C}$ (2)
3	Operating Temperature Range	$T_{op}$	-65 to +175	$^\circ\text{C}$	$T_{amb}$
4	Storage Temperature Range	$T_{stg}$	-65 to +200	$^\circ\text{C}$	
5	Soldering Temperature	$T_{sol}$	+260	$^\circ\text{C}$	Time: $\leq 10\text{s}$ Distance from case: $\geq 1.5\text{mm}$

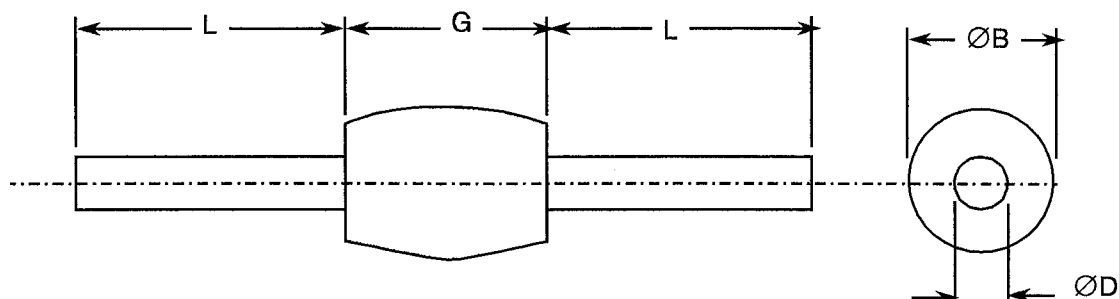
**NOTES**

1. No special mounting, heat-sinking or forced-air flow across exposed areas of the device is necessary.
2. For Derating, see Figure 1.



**FIGURE 1 - PARAMETER DERATING CHARACTERISTICS**



**FIGURE 2 - PHYSICAL DIMENSIONS**

SYMBOL	MILLIMETRES		INCHES		NOTES
	MIN.	MAX.	MIN.	MAX.	
$\varnothing B$	2.70	3.50	0.106	0.138	1
$\varnothing D$	0.75	0.85	0.030	0.033	
G	3.90	4.60	0.154	0.181	2
L	25.00	31.70	0.980	1.248	

**NOTES**

1. Dimension  $\varnothing B$  shall be measured at the largest diameter.
2. The 'G' dimension shall include all uncontrolled areas of the device leads.



**FIGURE 3 - FUNCTIONAL DIAGRAM**

1. Anode
2. Cathode

**NOTES**

1. The cathode end shall be marked with a contrasting coloured ring.



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**3. TERMS, DEFINITIONS, ABBREVIATIONS, SYMBOLS AND UNITS**

For the purpose of this specification, the terms, definitions, abbreviations, symbols and units specified in ESA/SCC Basic Specification No. 21300 shall apply.

**4. REQUIREMENTS**

**4.1 GENERAL**

The complete requirements for procurement of the diodes specified herein are stated in this specification and ESA/SCC Generic Specification No. 5000 for Discrete Semiconductors. Deviations from the Generic Specification applicable to this specification only, are listed in Para. 4.2.

Deviations from the applicable Generic Specification and this Detail Specification, formally agreed with specific Manufacturers on the basis that the alternative requirements are equivalent to the ESA/SCC requirements and do not affect the components' reliability, are listed in the appendices attached to this specification.

**4.2 DEVIATIONS FROM GENERIC SPECIFICATION**

**4.2.1 Deviations from Special In-process Controls**

None.

**4.2.2 Deviations from Final Production Tests (Chart II)**

- (a) Para. 9.2.1, Bond Strength Test: Shall not be performed.
- (b) Para. 9.2.2, Die-shear Test: Shall not be performed.
- (c) Para. 9.5, Thermal Shock Test: Shall be performed in accordance with MIL-STD-202, Test Method 107, Test Condition 'B'.
- (d) Para. 9.6, Constant Acceleration: Shall not be performed.
- (e) Para. 9.7, Particle Impact Noise Detection (PIND) Test: Not applicable.
- (f) Para's. 9.8.1 and 9.8.2, Seal Test: Shall not be performed.

**4.2.3 Deviations from Burn-in and Electrical Measurements (Chart III)**

- (a) Para. 9.22, H.T.R.B. Test: Shall not be performed.
- (b) Para's. 9.8.1 and 9.8.2, Seal Test: Shall not be performed.

**4.2.4 Deviations from Qualification Tests (Chart IV)**

- (a) Para. 9.2.3, Bond Strength Test: Shall not be performed.
- (b) Para. 9.2.4, Die-shear Test: Shall not be performed.
- (c) Para. 9.15, Constant Acceleration: Shall not be performed.
- (d) Para's. 9.8.1 and 9.8.2, Seal Test: Shall not be performed.

**4.2.5 Deviations from Lot Acceptance Tests (Chart V)**

- (a) Para. 9.15, Constant Acceleration: Shall not be performed.
- (b) Para's. 9.8.1 and 9.8.2, Seal Test: Shall not be performed.

**4.3 MECHANICAL REQUIREMENTS****4.3.1 Dimension Check**

The dimensions of the diodes specified herein shall be checked. They shall conform to those shown in Figure 2.

**4.3.2 Weight**

The maximum weight of the diodes specified herein shall be 0.5 grammes.

**4.3.3 Terminal Strength**

The requirements for terminal strength testing are specified in Section 9 of ESA/SCC Generic Specification No. 5000. The test conditions shall be as follows:-

Test Condition : 'A' (Tension).  
Applied Force : 10 Newtons.  
Duration : 10 seconds.



4.4 MATERIALS AND FINISHES

The materials and finishes shall be as specified herein. Where a definite material is not specified, a material which will enable the diodes specified herein to meet the performance requirements of this specification shall be used. Acceptance or approval of any constituent material does not guarantee acceptance of the finished product.

4.4.1 Case

The case shall be hermetically sealed and have a sintered glass body.

4.4.2 Lead Material and Finish

The lead material shall be Type 'K' with Type '3 or 4' finish in accordance with the requirements of ESA/SCC Basic Specification No. 23500. (See Table 1(a) for Type Variants).

4.5 MARKING

4.5.1 General

The marking of all components delivered to this specification shall be in accordance with the requirements of ESA/SCC Basic Specification No. 21700. Each component shall be marked in respect of:-

- (a) Lead Identification.
- (b) The SCC Component Number.
- (c) Traceability Information.

4.5.2 Lead Identification

Lead identification shall be as shown in Figure 3.

4.5.3 The SCC Component Number

Each component shall bear the SCC Component Number which shall be constituted and marked as follows:

Detail Specification Number \_\_\_\_\_ 510302504B  
Type Variant (see Table 1(a)) \_\_\_\_\_  
Testing Level (B or C, as applicable) \_\_\_\_\_

4.5.4 Traceability Information

Each component shall be marked in respect of traceability information in accordance with the requirements of ESA/SCC Basic Specification No. 21700.



#### 4.5.5 Marking of Small Components

When it is considered that the component is too small to accommodate the marking as specified above, as much as space permits shall be marked. The order of precedence shall be as follows:-

- (a) Lead Identification.
- (b) The SCC Component Number.
- (c) Traceability Information.

The marking information in full shall accompany each component in its primary package.

#### 4.6 ELECTRICAL MEASUREMENTS

##### 4.6.1 Electrical Measurements at Room Temperature

The parameters to be measured at room temperature are scheduled in Table 2. Unless otherwise specified, the measurements shall be performed at  $T_{amb} = +22 \pm 3$  °C.

##### 4.6.2 Electrical Measurements at High and Low Temperatures

The parameters to be measured at high and low temperatures are scheduled in Table 3.

##### 4.6.3 Circuits for Electrical Measurements

Circuits for use in performing the electrical measurements listed in Table 2 are shown in Figure 4 of this specification

#### 4.7 BURN-IN TESTS

##### 4.7.1 Parameter Drift Values

The parameter drift values applicable to burn-in are specified in Table 4 of this specification. Unless otherwise stated, the measurements shall be performed at  $T_{amb} = +22 \pm 3$  °C. The parameter drift values ( $\Delta$ ) applicable to the parameters scheduled, shall not be exceeded. In addition to these drift value requirements, the appropriate limit value specified for a given parameter in Table 2 shall not be exceeded.



4.7.2 Conditions for Power Burn-in

The requirements for power burn-in are specified in Section 7 of ESA/SCC Generic Specification No. 5000. The conditions for power burn-in shall be as shown in Table 5 of this specification.

4.7.3 Electrical Circuits for Power Burn-in (Figure 5)

Not applicable.

**TABLE 2 - ELECTRICAL MEASUREMENTS AT ROOM TEMPERATURE - d.c. PARAMETERS**

No.	CHARACTERISTICS	SYMBOL	TEST METHOD MIL-STD-750	TEST CONDITION	LIMITS		UNIT
					MIN.	MAX.	
1	Reverse Current	$I_R$	4016	$V_R = (1)$	-	1.0	$\mu A$
2	Forward Voltage	$V_F$	4011	$I_F = 1.0A$ See Note 2	-	0.875	Vdc
3	Breakdown Voltage	$V_{(BR)}$	4021	$I_R = 100\mu A$	(3)	-	Vdc

**NOTES**

1. See Column 3 of Table 1(a).
2. Pulsed Measurement: Pulse length  $\leq 500\mu s$ ; Duty Cycle  $\leq 2.5\%$ .
3. See Column 7 of Table 1(a).

**TABLE 2 - ELECTRICAL MEASUREMENTS AT ROOM TEMPERATURE - a.c. PARAMETERS**

No.	CHARACTERISTICS	SYMBOL	TEST METHOD MIL-STD-750	TEST CONDITION (Note 1)	LIMITS		UNIT
					MIN.	MAX.	
4	Reverse Recovery Time	$t_{rr}$	4031 Cond. 'B'	$I_F = 0.5A$ $I_R = 1.0A$ $I_{RR} = 0.25A$ See Figure 4	-	25	$\mu s$
5	Capacitance	C	4001	$V_R = 10V$ $V_{sig} = 50mV(p-p)$ $f = 1.0MHz$	-	60	pF
6	Forward Recovery Voltage	$V_{fr}$	4026	$I_{FM} = 0.25A$ $t_p \geq 20ns$ ; $t_r = 8ns$	-	2.2	Vdc
7	Forward Recovery Time	$t_{fr}$	4026	$I_{FM} = 0.25A$ $t_p \geq 20ns$ ; $t_r = 8ns$	-	15	ns

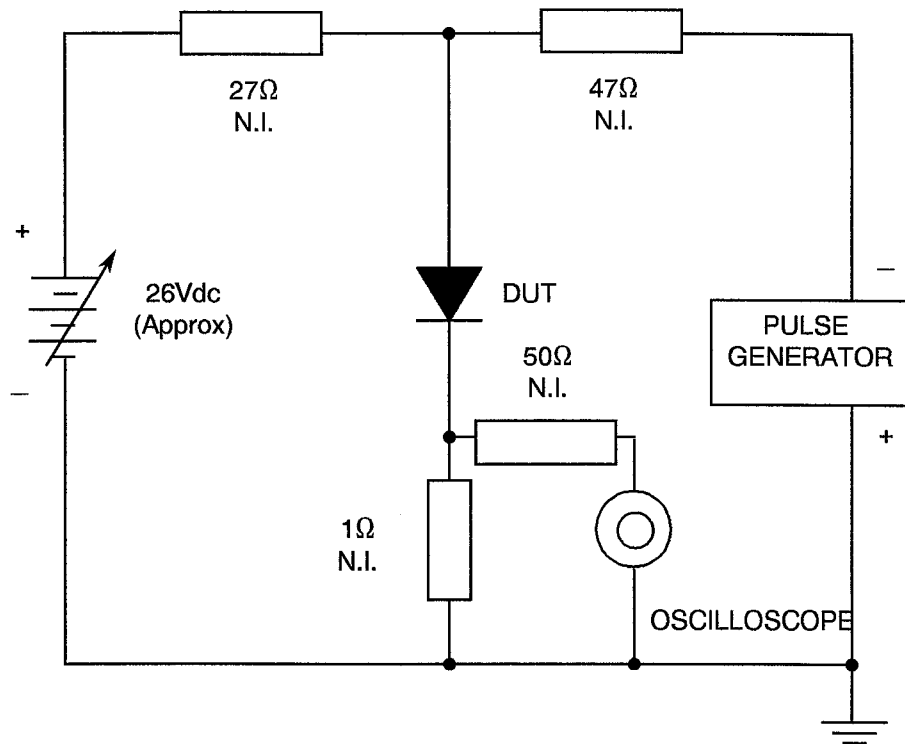
**NOTES**

1. Measurements performed on a sample basis, LTPD = 7 or less .



**FIGURE 4 - TEST CIRCUIT**

REVERSE RECOVERY TIME (OR EQUIVALENT)



**NOTES**

- 1. Oscilloscope :  $t_r \leq 7.0\text{ns}$ ;  $Z_{IN} = 1.0\text{M}\Omega$ ,  $22\text{pF}$ .
- 2. Pulse Generator :  $t_r \leq 10\text{ns}$ ;  $Z_S = 50\Omega$ .

**FIGURE 5 - ELECTRICAL CIRCUIT FOR POWER BURN-IN AND OPERATING LIFE TESTS**

Not applicable.

**TABLE 3 - ELECTRICAL MEASUREMENTS AT HIGH AND LOW TEMPERATURES**

No.	CHARACTERISTICS	SYMBOL	TEST METHOD MIL-STD-750	TEST CONDITIONS	LIMITS		UNIT
					MIN.	MAX.	
1	Reverse Current	$I_R$	4016	$V_R = (1)$ $T_{amb} = +100 (+0-5)^\circ C$	-	50	$\mu A$
2	Forward Voltage	$V_F$	4011	$I_F = 1.0A (2)$ $T_{amb} = +100 (+0-5)^\circ C$ $T_{amb} = -65 (+5-0)^\circ C$	-	0.8 1.1	Vdc
3	Breakdown Voltage	$V_{(BR)}$	4021	$I_R = 100\mu A$ $T_{amb} = -65 (+5-0)^\circ C$	(3)	-	Vdc

**NOTES**

1. See Column 3 of Table 1(a).
2. Pulsed Measurement: Pulse length  $\leq 500\mu s$ ; Duty Cycle:  $\leq 2.5\%$ .
3. See Column 7 of Table 1(a).

**TABLE 4 - PARAMETER DRIFT VALUES**

No.	CHARACTERISTICS	SYMBOL	SPEC. AND/OR TEST METHOD	TEST CONDITION	CHANGE LIMITS ( $\Delta$ )	UNIT
1	Reverse Current	$I_R$	As per Table 2	As per Table 2	$\pm 100.$ or (1) $\pm 250$	% nA
2	Forward Voltage	$V_F$	As per Table 2	As per Table 2	$\pm 100$	mV

**NOTES**

1. Whichever is the greater referred to the initial value.

**TABLE 5 - CONDITIONS FOR POWER BURN-IN AND OPERATING LIFE TESTS**

No.	CHARACTERISTICS	SYMBOL	CONDITION	UNIT
1	Ambient Temperature	$T_{amb}$	$+25 \pm 3$	$^\circ C$
2	Peak Reverse Working Voltage	$V_{RWM}$	See Column 4 of Table 1(a)	V
3	Average Forward Current	$I_O$	1.0 (1)	A <sub>dc</sub>
4	Frequency	f	50	Hz

**NOTES**

1.  $I_O$  is adjusted to maintain  $T_J$  at  $T_{amb}$  plus  $120^\circ C$  minimum.



**4.8 ENVIRONMENTAL AND ENDURANCE TESTS (CHARTS IV AND V OF ESA/SCC GENERIC SPECIFICATION NO. 5000)****4.8.1 Electrical Measurements on Completion of Environmental Tests**

The parameters to be measured on completion of environmental tests are scheduled in Table 2. The measurements shall be performed at  $T_{amb} = +22 \pm 3$  °C.

**4.8.2 Electrical Measurements at Intermediate Points and on Completion of Endurance Tests**

The parameters to be measured at intermediate points and on completion of endurance testing are scheduled in Table 6. The measurements shall be performed at  $T_{amb} = +22 \pm 3$  °C.

**4.8.3 Conditions for Operating Life Tests (Part of Endurance Testing)**

The requirements for operating life testing are specified in Section 9 of ESA/SCC Generic Specification No. 5000. The conditions for operating life testing shall be as specified in Table 5 for the burn-in test.

**4.8.4 Electrical Circuits for Operating Life Tests (Figure 5)**

Not applicable.

**4.8.5 Conditions for High Temperature Storage Test (Part of Endurance Testing)**

The requirements for the high temperature storage test are specified in ESA/SCC Generic Specification No. 5000. The conditions for high temperature storage shall be the maximum storage temperature specified in Table 1(b) of this specification.

**TABLE 6 - ELECTRICAL MEASUREMENTS AT INTERMEDIATE POINTS AND ON COMPLETION OF ENDURANCE TESTING**

No.	CHARACTERISTICS	SYMBOL	SPEC. AND/OR TEST METHOD	TEST CONDITION	LIMITS		UNIT
					MIN.	MAX.	
1	Reverse Current	$I_R$	As per Table 2	As per Table 2	-	1.0	$\mu A$
2	Forward Voltage	$V_F$	As per Table 2	As per Table 2	-	0.875	Vdc